

Supporting Information

The electronic and magnetic properties modulated by ferroelectric polarization switching in two-dimensional VSeTe/Sc₂CO₂ van der Waals heterostructure

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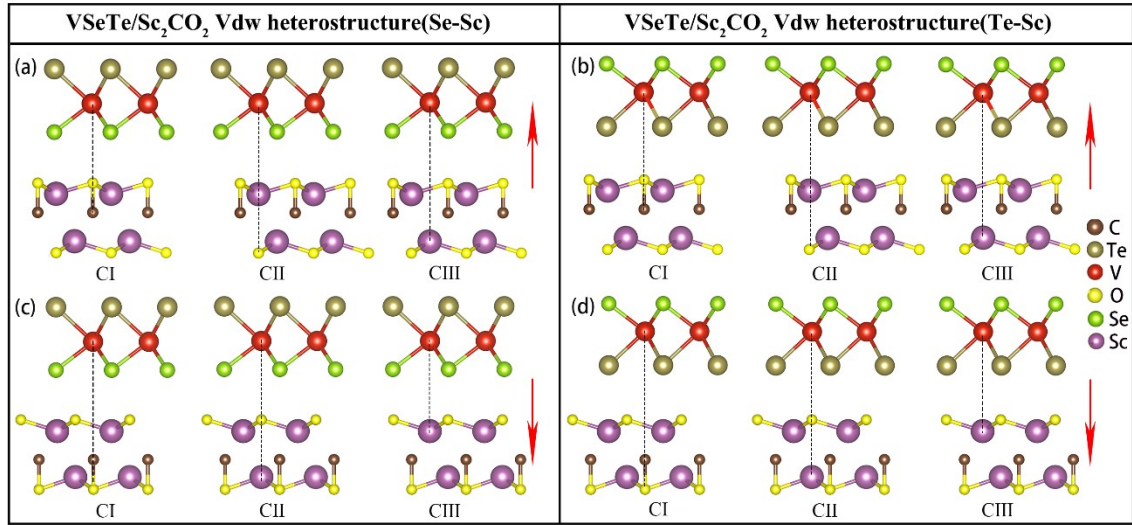


Fig. S1 12 kinds of heterogeneous structural types. Among them, (a) and (b) are three highly symmetric configurations with ferroelectric polarization upward of Se-Sc and Te-Sc as the contact surface; (c) and (d) are three highly symmetrical configurations with ferroelectric polarization downward of Se-Sc and Te-Sc as the contact surface.

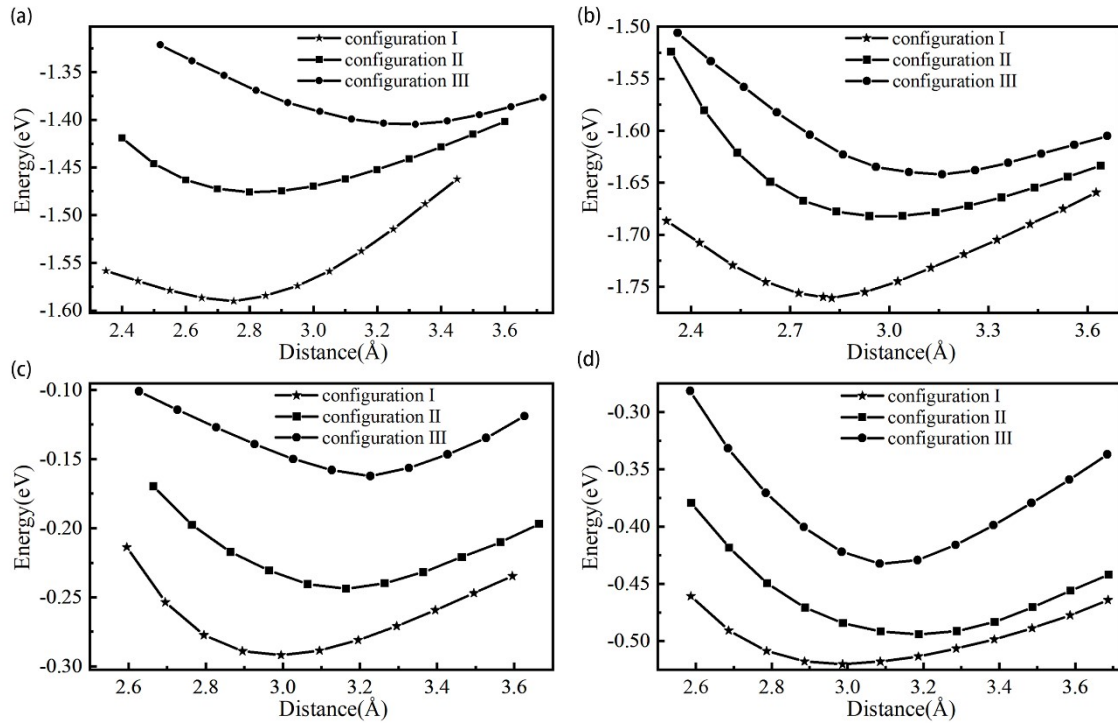


Fig. S2 Relationship between layer spacing and energy of 12 kinds of configurations. Where (a) and (b) are ferroelectric polarization upward and downward heterostructure with Se-Sc as contact surface, respectively. (c) and (d) represent the upward and downward heterostructure

of ferroelectric polarization with Te-Sc as the contact surface, respectively. Star, square and round dots represent CI, CII and CIII configurations, respectively.

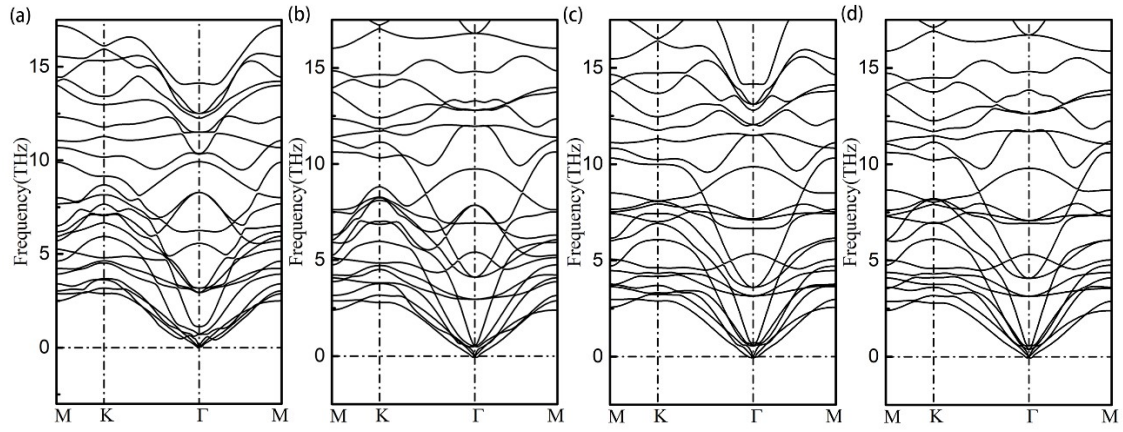


Fig. S3 Phonon spectra corresponding to the four lowest energy configurations: (a) VSeTe/Sc₂CO₂ (Se-Sc↑), (b) VSeTe/Sc₂CO₂ (Se-Sc↓), (c) VSeTe/Sc₂CO₂ (Te-Sc↑), (d) VSeTe/Sc₂CO₂ (Te-Sc↓).

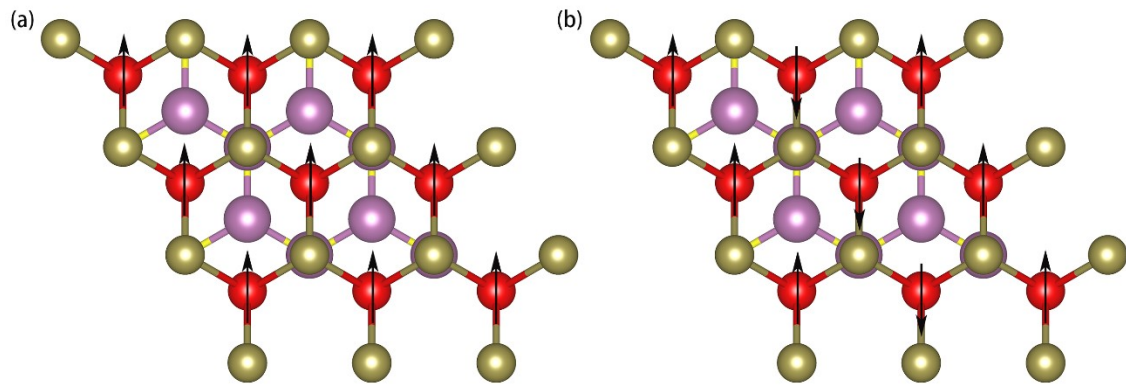


Fig. S4 Ferromagnetic configurations of VSeTe/Sc₂CO₂ (Se-Sc↑) heterostructure with (a) ferromagnetic and (b) antiferromagnetic configuration.

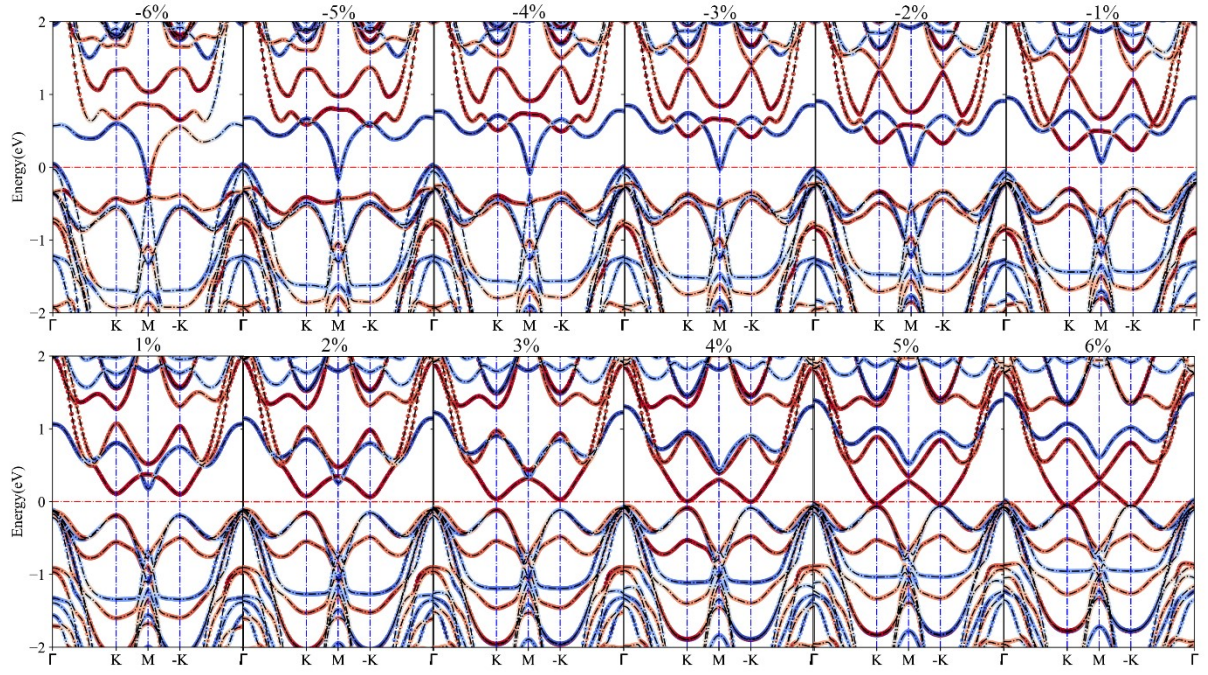


Fig. S5 Band structures of VSeTe/Sc₂CO₂ (Se-Sc↓) heterostructures regulated by strain.

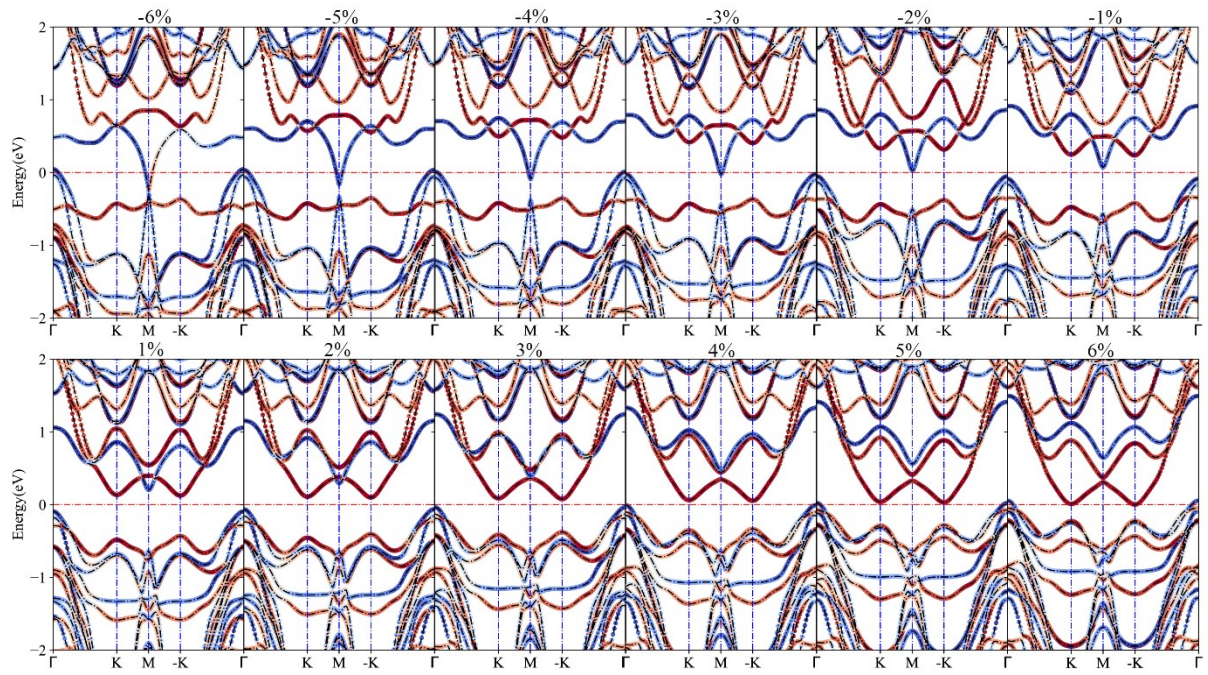


Fig. S6 Band structures of VSeTe/Sc₂CO₂ (Te-Sc↓) heterostructures regulated by strain.